- Operating Range of 2 V to 5.5 V
- Max t<sub>pd</sub> of 10 ns at 5 V
- Low Power Consumption, 10-μA Max I<sub>CC</sub>
- ±8-mA Output Drive at 5 V
- Latch-Up Performance Exceeds 250 mA Per JESD 17

# NC 1 5 V<sub>CC</sub> A 2 GND 3 4 Y

NC - No internal connection

### description/ordering information

The SN74AHC1G14 contains one inverter gate. The device performs the Boolean function  $Y = \overline{A}$ .

The device functions as an independent inverter gate, but because of the Schmitt action, gates may have different input threshold levels for positive-  $(V_{T+})$  and negative-going  $(V_{T-})$  signals.

#### ORDERING INFORMATION

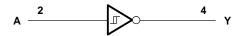
TA	PACKAGE	<u>:</u> †	ORDERABLE PART NUMBER	TOP-SIDE MARKING‡	
	SOT (SOT-23) – DBV	Reel of 3000	SN74AHC1G14DBVR	A14	
4000 / 0500	301 (301-23) – DBV	Reel of 250	SN74AHC1G14DBVT	A14_	
-40°C to 85°C			SN74AHC1G14DCKR	AF	
	SOT (SC-70) – DCK	Reel of 250	SN74AHC1G14DCKT	Ar_	

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

#### **FUNCTION TABLE**

INPUT A	OUTPUT Y
Н	L
L	Н

### logic diagram (positive logic)





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



<sup>&</sup>lt;sup>‡</sup>The actual top-side marking has one additional character that designates the assembly/test site.

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>	–0.5 V to 7 V
Input voltage range, V <sub>I</sub> (see Note 1)	–0.5 V to 7 V
Output voltage range, VO (see Note 1)	–0.5 V to V <sub>CC</sub> + 0.5 V
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)	–20 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>CC</sub> )	±20 mA
Continuous output current, $I_O$ ( $V_O = 0$ to $V_{CC}$ )	±25 mA
Continuous current through V <sub>CC</sub> or GND	±50 mA
Package thermal impedance, θ <sub>JA</sub> (see Note 2): DBV package	206°C/W
DCK package	252°C/W
Storage temperature range, T <sub>stg</sub>	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### recommended operating conditions (see Note 3)

					UNIT
Vcc	V <sub>CC</sub> Supply voltage				V
٧ı	V <sub>I</sub> Input voltage				V
Vo	Output voltage	Itage			
		V <sub>CC</sub> = 2 V		-50	μΑ
IOH	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4	mA
	$V_{CC} = 5 V \pm 0.5 V$			-8	ША
		V <sub>CC</sub> = 2 V		50	μΑ
lOL	Low-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4	mΑ
	$V_{CC} = 5 V \pm 0.5 V$			8	ША
T <sub>A</sub> Operating free-air temperature				85	°C

NOTE 3: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>2.</sup> The package thermal impedance is calculated in accordance with JESD 51-7.

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	Vaa	T,	4 = 25°C	;	MINI	MIN MAX	UNIT
PARAMETER		Vcc	MIN	TYP	MAX	IVIIIN		ONIT
V <sub>T+</sub>		3 V	1.2		2.2	1.2	2.2	
Positive-going		4.5 V	1.75		3.15	1.75	3.15	V
input threshold voltage		5.5 V	2.15		3.85	2.15	3.85	
V <sub>T</sub> _		3 V	0.9		1.9	0.9	1.9	
Negative-going		4.5 V	1.35		2.75	1.35	2.75	V
input threshold voltage		5.5 V	1.65		3.35	1.65	3.35	
$\Delta V_T$ Hysteresis ( $V_{T+} - V_{T-}$ )		3 V	0.3		1.2	0.3	1.2	
		4.5 V	0.4		1.4	0.4	1.4	V
		5.5 V	0.5		1.6	0.5	1.6	
		2 V	1.9	2		1.9		
	I <sub>OH</sub> = -50 μA	3 V	2.9	3		2.9		
VOH		4.5 V	4.4	4.5		4.4		V
	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.48		
	$I_{OH} = -8 \text{ mA}$	4.5 V	3.94			3.8		
		2 V			0.1		0.1	
	I <sub>OL</sub> = 50 μA	3 V			0.1		0.1	V
V <sub>OL</sub>		4.5 V			0.1		0.1	
	I <sub>OL</sub> = 4 mA	3 V			0.36		0.44	
	I <sub>OL</sub> = 8 mA	4.5 V			0.36		0.44	
lį	V <sub>I</sub> = 5.5 V or GND	0 V to 5.5 V			±0.1		±1	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			1		10	μΑ
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	5 V		2	10		10	pF

# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 3.3 V $\pm$ 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO LOAD CAPACITANCE	TO LOAD		T <sub>A</sub> = 25°C			MAX	UNIT		
PARAMETER	(INPUT)		MIN	TYP	MAX	MIN	IVIAA	UNIT			
<sup>t</sup> PLH	Δ	Y	V 0: 45 mE	A V 0. 45.	C: 45 pF		8.3	12.8	1	15	
<sup>t</sup> PHL	А		C <sub>L</sub> = 15 pF	CL = 15 pr -		8.3	12.8	1	15	ns	
<sup>t</sup> PLH	Δ	Υ	Y	C 50 pF		10.8	16.3	1	18.5	20	
tPHL	А			C <sub>L</sub> = 50 pF		10.8	16.3	1	18.5	ns	

# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 5 V $\pm$ 0.5 V (unless otherwise noted) (see Figure 1)

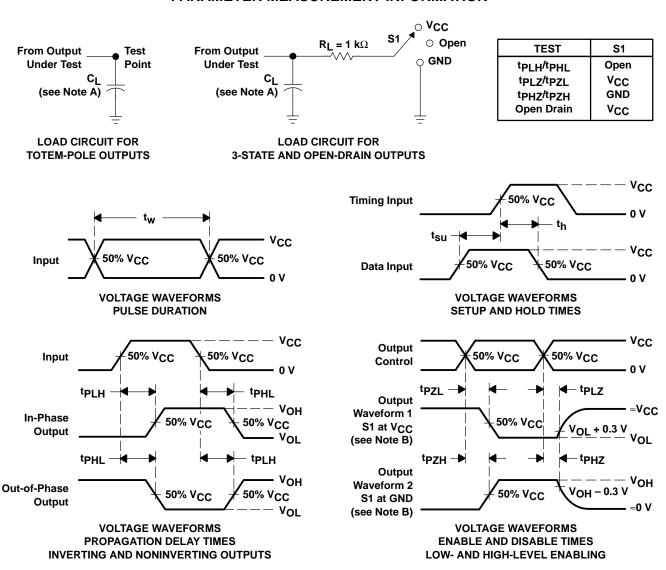
PARAMETER	FROM T	то	LOAD	T <sub>A</sub> = 25°C			MIN N	MAX	UNIT	
PARAMETER	(INPUT)	(OUTPUT) C	CAPACITANCE	MIN	TYP	MAX		IVIAA	UNIT	
<sup>t</sup> PLH	Δ.	V	C 15 pE		5.5	8.6	1	10	no	
<sup>t</sup> PHL	А	ī	Y $C_L = 15 \text{ pF}$		5.5	8.6	1	10	ns	
<sup>t</sup> PLH	۸	<sup>t</sup> PLH ,	A V C 50 pE		7	10.6	1	12	20	
<sup>t</sup> PHL	А	ſ	CL = 50 pF	C <sub>L</sub> = 50 pF		7	10.6	1	12	ns



### operating characteristics, V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C

PARAMETER		TEST CO	ONDITIONS	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance	No load,	f = 1 MHz	9	pF

### PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ ,  $t_r \leq 3$  ns.  $t_f \leq 3$  ns.
  - D. The outputs are measured one at a time with one input transition per measurement.
  - E. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



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